

LOW NOISE AMPLIFIER GaAs MMIC

■GENERAL DESCRIPTION

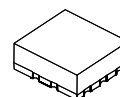
NJG1107HB3 is a Low Noise Amplifier GaAs MMIC designed for GPS. This amplifier provides low noise figure, high gain and high IP3 operated by single low positive power supply.

This amplifier includes internal self-bias circuit and input DC blocking capacitor.

This amplifier can be tuned to wide frequency point (1.5GHz~2.4GHz).

An ultra small and ultra thin package of USB8-B3 is adopted.

■PACKAGE OUTLINE

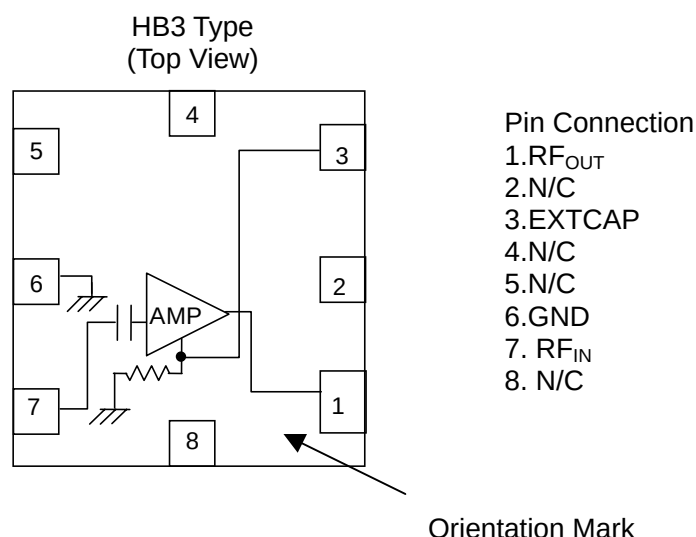


NJG1107HB3

■FEATURES

- | | |
|-----------------------------------|--|
| ●Low voltage operation | +2.7V typ. |
| ●Low current consumption | 2.5mA typ. |
| ●High small signal gain | 17dB typ. @f=1.575GHz |
| ●Low noise figure | 1.1dB typ. @f=1.575GHz |
| ●High Input IP3 | -4.0dBm typ. @f=1.575+1.5751GHz |
| ●Ultra small & ultra thin package | USB8-B3 (Package size: 1.5x1.5x0.75mm) |

■PIN CONFIGURATION



Note: Specifications and description listed in this catalog are subject to change without prior notice.

NJG1107HB3

■ABSOLUTE MAXIMUM RATINGS

($T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\text{ohm}$)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Drain Voltage	V_{DD}		6.0	V
Input Power	Pin	$V_{DD}=2.7\text{V}$	+15	dBm
Power Dissipation	P_D	At on PCB board	135	mW
Operating Temp.	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage Temp.	T_{stg}		-55~+150	$^{\circ}\text{C}$

■ELECTRICAL CHARACTERISTICS

($V_{DD}=2.7\text{V}$, $f=1.575\text{GHz}$, $T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\text{ohm}$, TEST CIRCUIT)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Frequency	freq1		1.57	1.575	1.58	GHz
Drain Voltage	V_{DD}		2.5	2.7	5.5	V
Operating Current	I_{DD}	RF OFF	-	2.5	3.2	mA
Small Signal Gain	Gain		15.0	17.0	-	dB
Noise Figure	NF		-	1.1	1.3	dB
Pin at 1dB Gain Compression point	$P_{-1\text{dB}}$		-20.0	-16.0	-	dBm
Input 3rd Order Intercept Point	IIP3	$f=1.575+1.5751\text{GHz}$ $RFin=-35\text{dBm}$	-6.0	-4.0	-	dBm
RF Input Port VSWR	$VSWR_i$		-	1.6	2.0	
RF Output Port VSWR	$VSWR_o$			1.6	2.0	

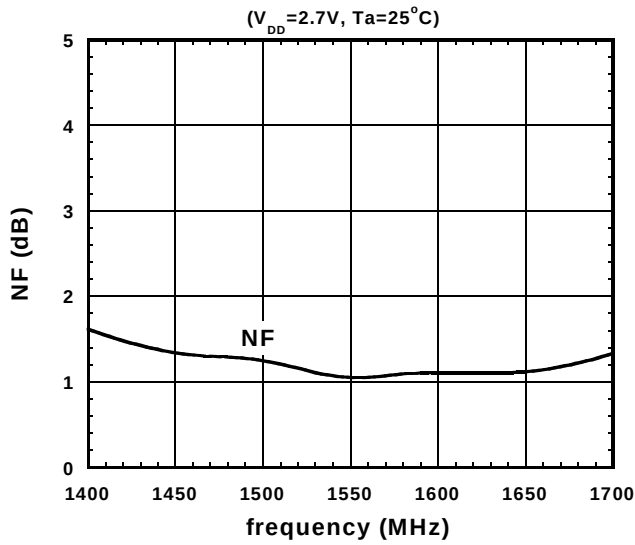
■PIN CONFIGURATION

Pin	Function	Description
1	Rfout	RF output and voltage supply pin. External matching circuits and a bypass capacitor is required. L3 is a RF choke inductor and C1 is a DC blocking capacitor. These elements are used as output matching circuit. C2 is a bypass capacitor.
2,4,5,8	N/C	Neutral terminal. Should be connected to the ground.
3	EXTCAP	An external bypass capacitor is required.
6	GND	Ground pin. To keep good RF grounding performance, please use multiple via holes to connect with ground plane and this pin.
7	Rfin	RF input pin. A DC blocking capacitor is not required. An external matching circuit is required.

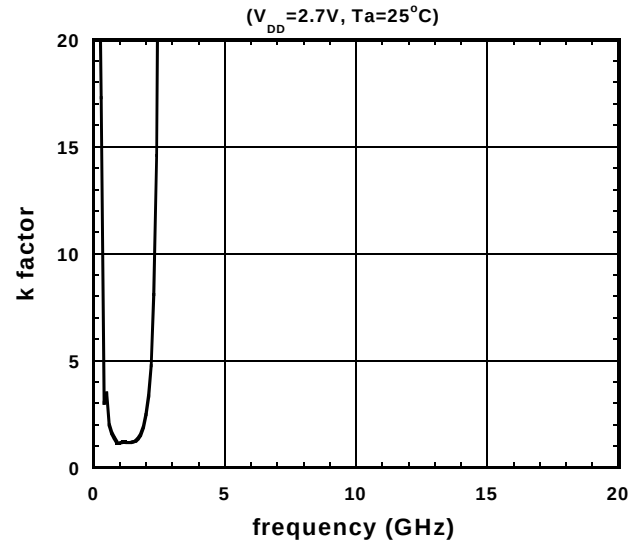
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TYPICAL CHARACTERISTICS

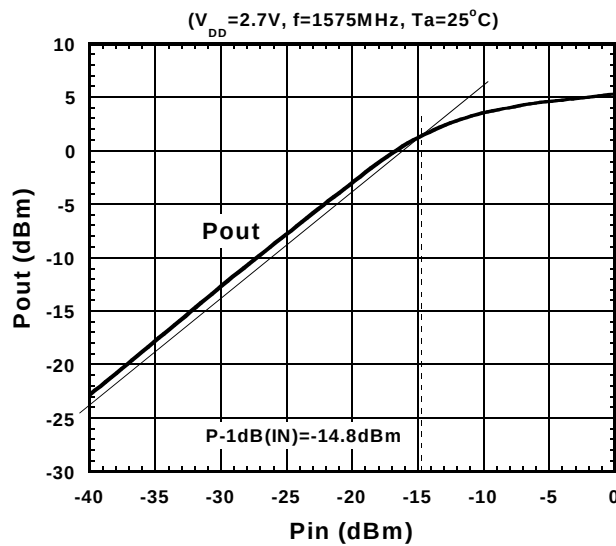
NF vs. frequency



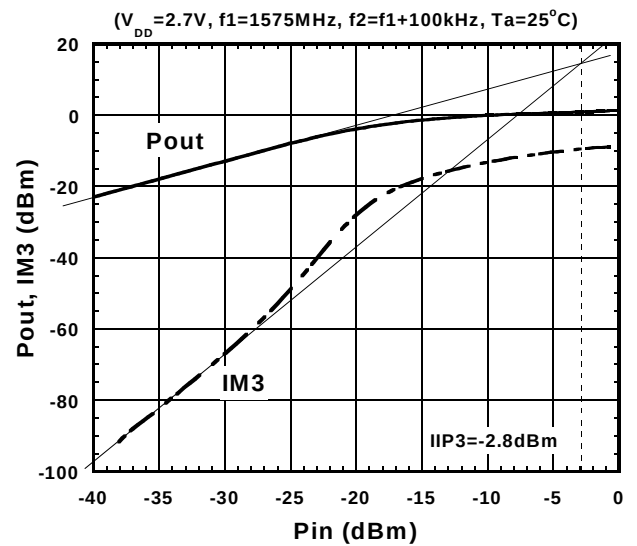
k factor vs. frequency



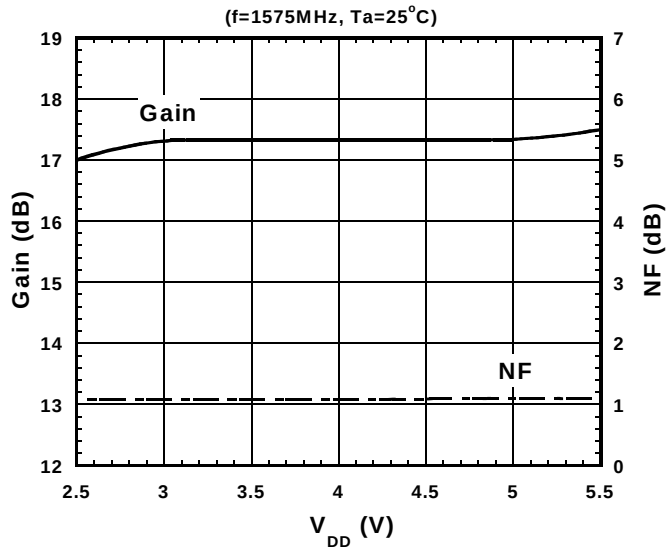
Pout vs. Pin



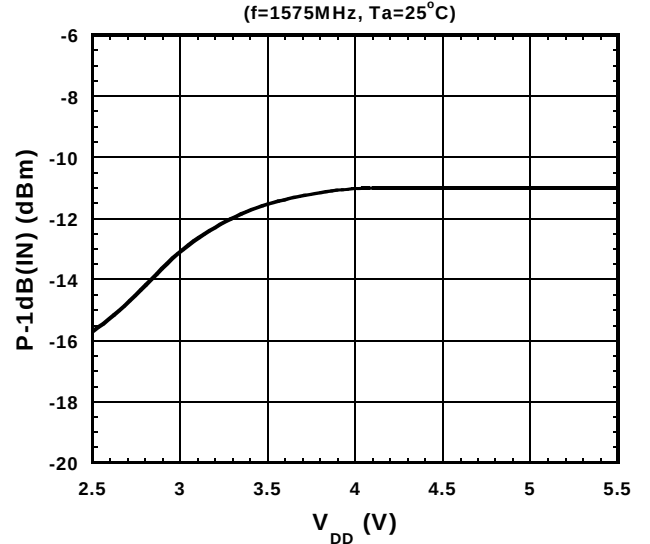
Pout, IM3 vs. Pin



Gain, NF vs. V_{DD}

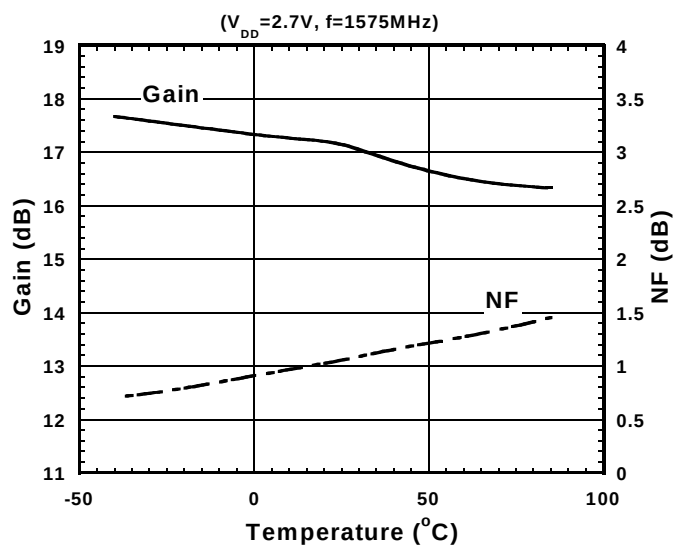


P-1dB(IN) vs. V_{DD}

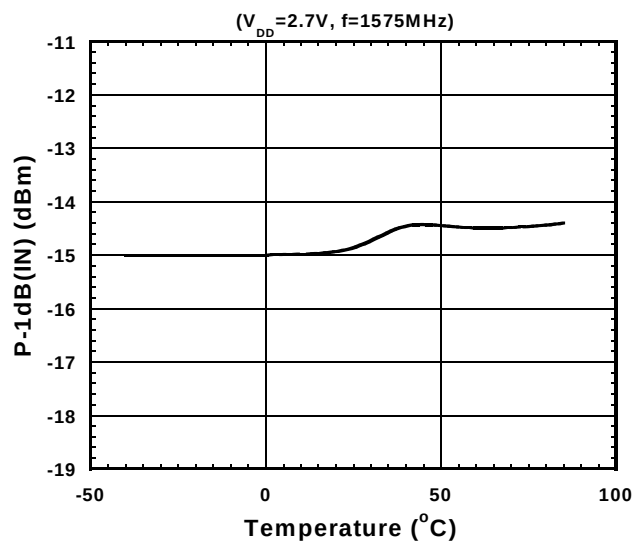


TYPICAL CHARACTERISTICS

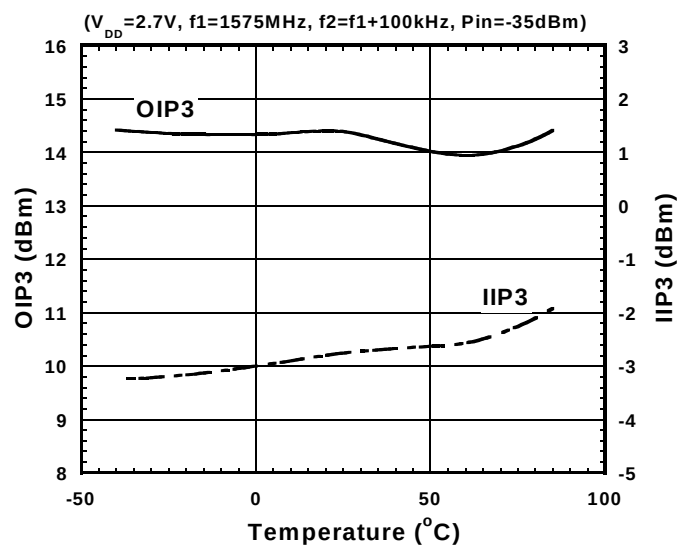
Gain, NF vs. Temperature



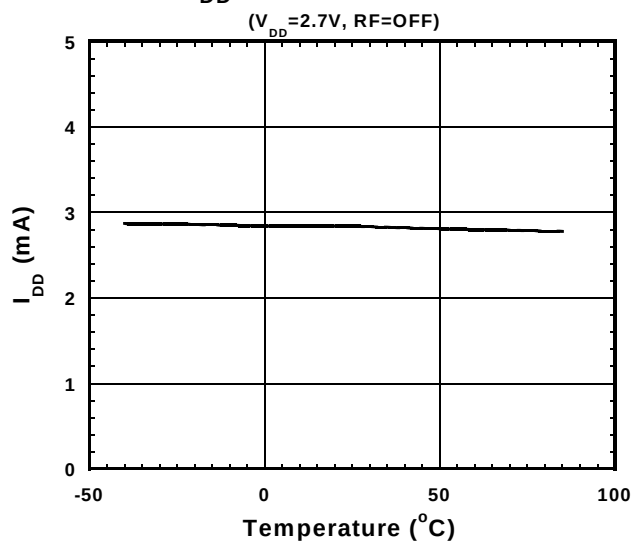
P-1dB(IN) vs. Temperature



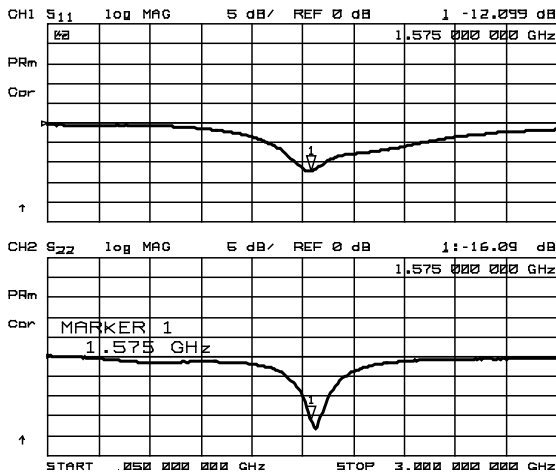
OIP3, IIP3 vs. Temperature



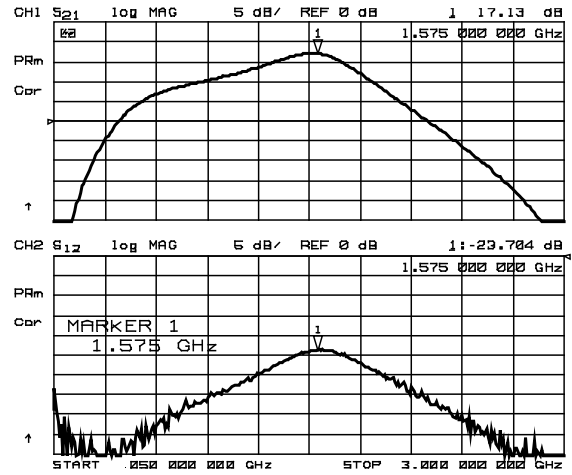
I_{DD} vs. Temperature



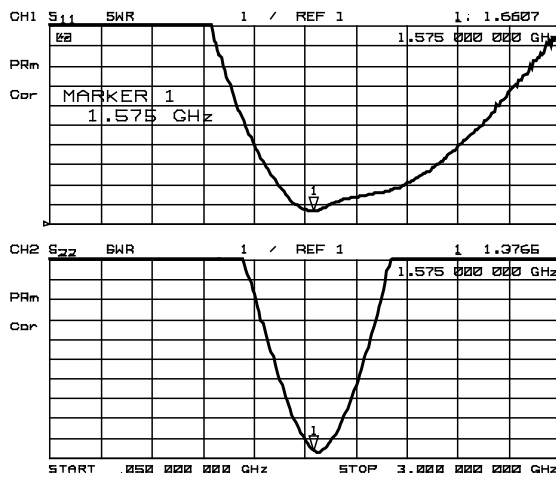
TYPICAL CHARACTERISTICS



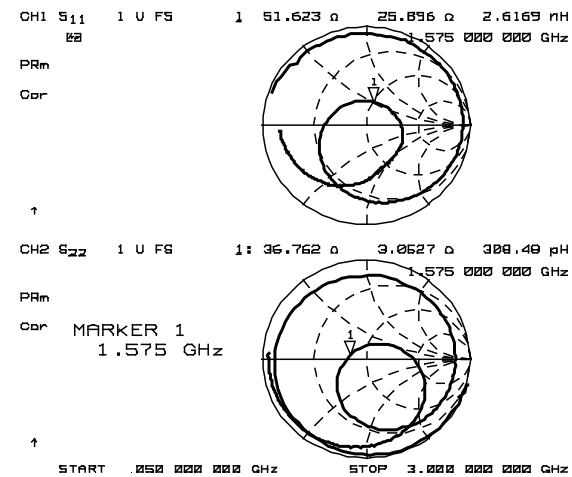
S₁₁, S₂₂



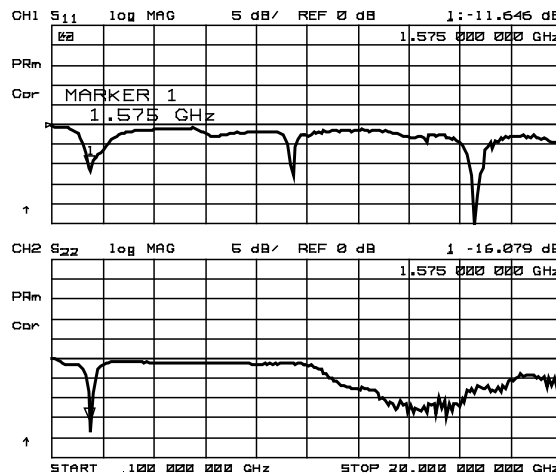
S₂₁, S₁₂



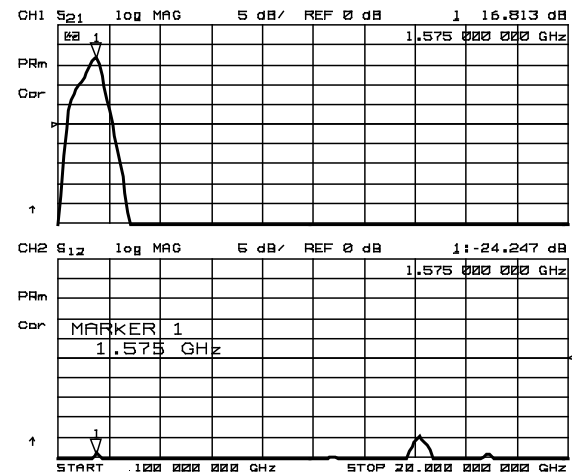
VSWR



Z_{in}, Z_{out}

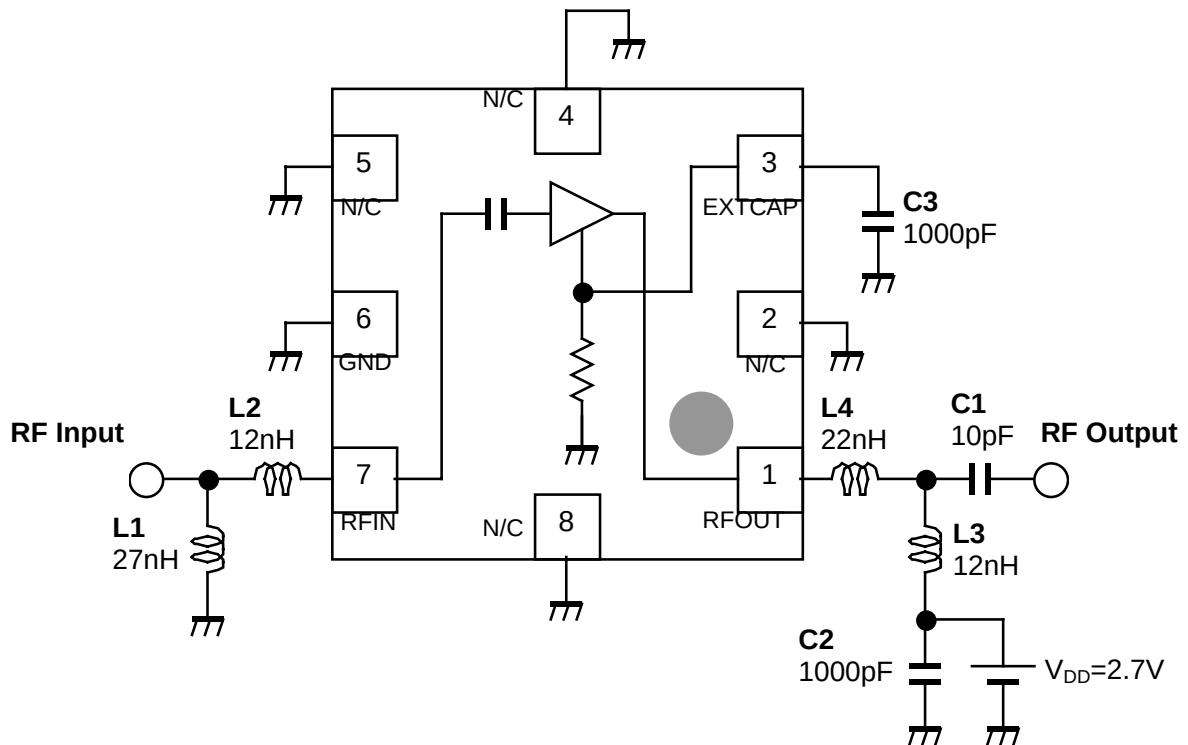


S₁₁, S₂₂(~20GHz)



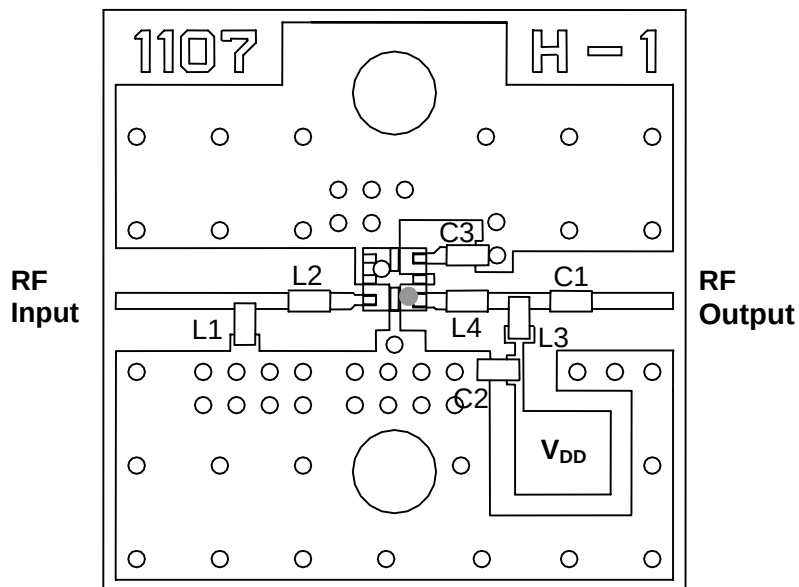
S₂₁, S₁₂(~20GHz)

TEST CIRCUIT



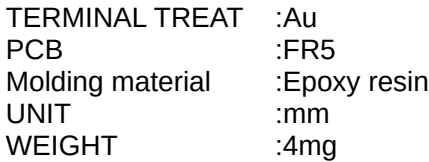
RECOMMENDED PCB DESIGN

(Top View)



Parts ID	Comment
L1, L3, L4	TDK (MLK1005)
L2	TDK (MLG1005)
C1~C3	MURATA (GRP15)

PCB (FR-4):
 $t=0.2\text{mm}$
 MICROSTRIP LINE WIDTH
 $=0.4\text{mm}$ ($Z_0=50\text{ohm}$)
 PCB SIZE= $14.0\text{mm} \times 14.0\text{mm}$



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